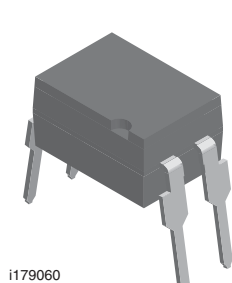
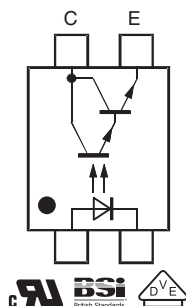


Optocoupler, Photodarlington Output



i179060



FEATURES

- High isolation test voltage 5300 V_{RMS}
- Standard plastic DIP-4 package
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC


RoHS
COMPLIANT

AGENCY APPROVALS

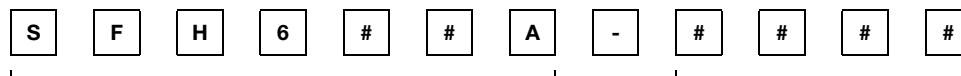
- UL - file no. E52744 system code H, double protection
- DIN EN 60747-5-2 (VDE 0884), IEC 60747-5-5
- DIN EN 60747-5-5 (VDE 0884) pending
- BSI IEC 60950; IEC 60065

DESCRIPTION

The SFH655A is optically coupled isolators with a gallium arsenide infrared LED and a silicon photodarlington detector. Switching can be achieved while maintaining a high degree of isolation between driving and load circuits.

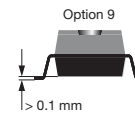
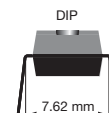
This optocouplers can be used to replace reed and mercury relays with advantages of long life, high speed switching and elimination of magnetic fields.

ORDERING INFORMATION



PART NUMBER

PACKAGE OPTION



AGENCY CERTIFIED/PACKAGE	CTR (%)
cUL, VDE	> 600
DIP-4	SFH655A
SMD-4, option 9	SFH655A-X009

Note

- For additional information on the available options refer to option information.

ABSOLUTE MAXIMUM RATINGS (T_{amb} = 25 °C, unless otherwise specified)

PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
INPUT				
Peak reverse voltage		V _{RM}	6	V
Forward continuous current		I _F	60	mA
Surge forward current	t _p ≤ 10μs	I _{FSM}	2.5	A
Derate linearly from 25 °C			1.33	mW/°C
Power dissipation		P _{diss}	100	mW
OUTPUT				
Collector emitter breakdown voltage		BV _{CEO}	55	V
Emitter collector breakdown voltage		BV _{ECO}	6	V
Collector (load) current		I _C	125	mA
Derate linearly from 25 °C			2	mW/°C
Power dissipation		P _{diss}	150	mW

ABSOLUTE MAXIMUM RATINGS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
COUPLER				
Derate linearly from 25 $^{\circ}\text{C}$			3.33	mW/ $^{\circ}\text{C}$
Total power dissipation		P_{tot}	250	mW
Isolation voltage		V_{IORM}	890	V_P
Isolation test voltage between input and output, climate acc. to IEC 60068 - 1:1988		V_{ISO}	5300	V_{RMS}
Creepage distance			≥ 7	mm
Clearance distance			≥ 7	mm
Comparative tracking index acc. to DIN IEC 112/VDE 0303, part 1:06-84			≥ 175	
Isolation resistance	$V_{IO} = 500\text{ V}, T_{amb} = 25\text{ }^{\circ}\text{C}$	R_{IO}	$\geq 10^{12}$	Ω
	$V_{IO} = 500\text{ V}, T_{amb} = 100\text{ }^{\circ}\text{C}$	R_{IO}	$\geq 10^{11}$	Ω
Storage temperature range		T_{stg}	- 55 to + 150	$^{\circ}\text{C}$
Operating temperature range		T_{amb}	- 55 to + 100	$^{\circ}\text{C}$
Soldering temperature ⁽¹⁾	max. 10 s, dip soldering distance to seating plane $\geq 1.5\text{ mm}$	T_{sld}	260	$^{\circ}\text{C}$

Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.
- ⁽¹⁾ Refer to reflow profile for soldering conditions for surface mounted devices (SMD). Refer to wave profile for soldering conditions for through hole devices (DIP).

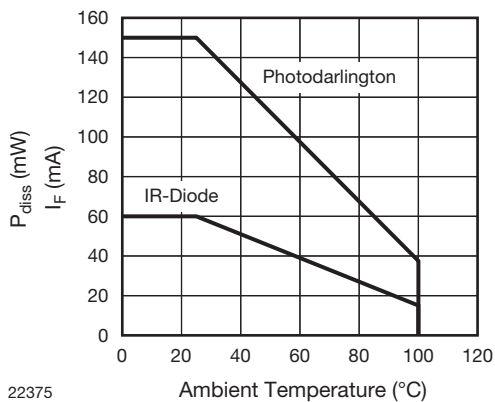


Fig. 1 - Power Dissipation vs. Ambient Temperature



ELECTRICAL CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT							
Forward voltage	$I_F = 10\text{ mA}$		V_F		1.15	1.5	V
Reverse current	$V_R = 6\text{ V}$		I_R		0.02	10	μA
Capacitance	$V_R = 0\text{ V}$, $f = 1\text{ MHz}$		C_O		50		pF
OUTPUT							
Collector emitter breakdown voltage	$I_{CE} = 100\text{ }\mu\text{A}$		BV_{CEO}	55			V
Emitter collector breakdown voltage	$I_{EC} = 10\text{ }\mu\text{A}$		BV_{ECO}	6			V
Collector emitter dark current	$V_{CE} = 40\text{ V}$		I_{CEO}		12	400	nA
Collector emitter capacitance	$V_{CE} = 0\text{ V}$, $f = 1\text{ MHz}$		C_{CE}		13.5		pF
COUPLER							
Collector emitter saturation voltage	$I_F = 20\text{ mA}$, $I_C = 5\text{ mA}$	SFH655A	V_{CEsat}			1	V
Coupling capacitance	$V_{I-O} = 0\text{ V}$, $f = 1\text{ MHz}$		C_C		0.45		pF

Note

- Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Current transfer ratio	$I_F = 1\text{ mA}$, $V_{CE} = 2\text{ V}$	SFH655A	CTR	600			%

SAFETY AND INSULATION RATED PARAMETERS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Partial discharge test voltage - routine test	100 %, $t_{test} = 1\text{ s}$	V_{pd}	1.669			kV
Partial discharge test voltage - lot test (sample test)	$t_{Tr} = 60\text{ s}$, $t_{test} = 10\text{ s}$, (see fig. 2)	V_{pd}	1.424			kV
Insulation resistance	$V_{IO} = 500\text{ V}$	R_{IO}	10^{12}			Ω
	$V_{IO} = 500\text{ V}$, $T_{amb} = 100\text{ }^{\circ}\text{C}$	R_{IO}	10^{11}			Ω
	$V_{IO} = 500\text{ V}$, $T_{amb} = 150\text{ }^{\circ}\text{C}$ (construction test only)	R_{IO}	10^9			Ω
Climatic classification (according to IEC 68 part 1)				55/100/21		
Comparative tracking index		CTI	175		399	
Creepage distance	standard DIP-4		7			mm
Clearance distance	standard DIP-4		7			mm
Insulation thickness, reinforced rated	per IEC 60950 2.10.5.1		0.4			mm
Forward current		I_{si}			275	mA
Power dissipation		P_{so}			400	mW
Safety temperature		T_{si}			175	$^{\circ}\text{C}$

Note

- According to DIN EN 60747-5-2 (VDE 0884) (see fig. 2). This optocoupler is suitable for safe electrical isolation only within the safety ratings. Compliance with the safety ratings shall be ensured by means of suitable protective circuits.

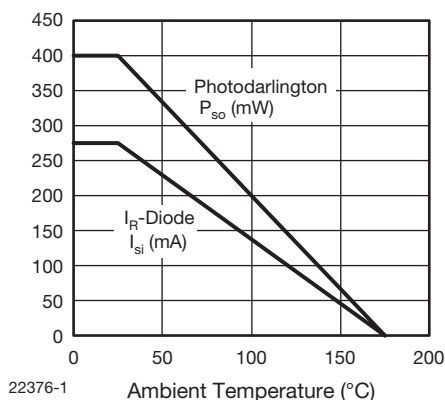


Fig. 2 - Derating Diagram

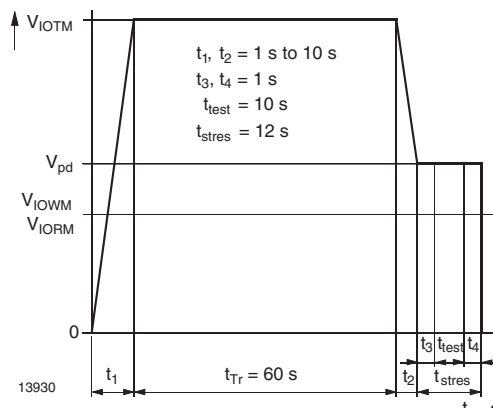


Fig. 3 - Test Pulse Diagram for Sample Test according to DIN EN 60747-5-2 (VDE 0884); IEC 60747-5-5

SWITCHING CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Turn-on time (fig. 10, test circuit 1)	$V_{CC} = 10\text{ V}$, $I_C = 2\text{ mA}$, $R_L = 100\text{ }\Omega$	SFH612A	t_{on}		16		μs
Turn-off time (fig. 10, test circuit 1)	$V_{CC} = 10\text{ V}$, $I_C = 2\text{ mA}$, $R_L = 100\text{ }\Omega$	SFH612A	t_{off}		15		μs
Rise time (fig. 10, test circuit 1)	$V_{CC} = 10\text{ V}$, $I_C = 2\text{ mA}$, $R_L = 100\text{ }\Omega$	SFH612A	t_r		14		μs
Fall time (fig. 10, test circuit 1)	$V_{CC} = 10\text{ V}$, $I_C = 2\text{ mA}$, $R_L = 100\text{ }\Omega$	SFH612A	t_f		14		μs
Turn-on time (fig. 11, test circuit 2)	$V_{CC} = 2\text{ V}$, $I_C = 10\text{ mA}$, $R_L = 100\text{ }\Omega$	SFH655A	t_{on}		31		μs
Turn-off time (fig. 11, test circuit 2)	$V_{CC} = 2\text{ V}$, $I_C = 10\text{ mA}$, $R_L = 100\text{ }\Omega$	SFH655A	t_{off}		55		μs
Rise time (fig. 11, test circuit 2)	$V_{CC} = 2\text{ V}$, $I_C = 10\text{ mA}$, $R_L = 100\text{ }\Omega$	SFH655A	t_r		27	250	μs
Fall time (fig. 11, test circuit 2)	$V_{CC} = 2\text{ V}$, $I_C = 10\text{ mA}$, $R_L = 100\text{ }\Omega$	SFH655A	t_f		56	200	μs

TYPICAL CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)

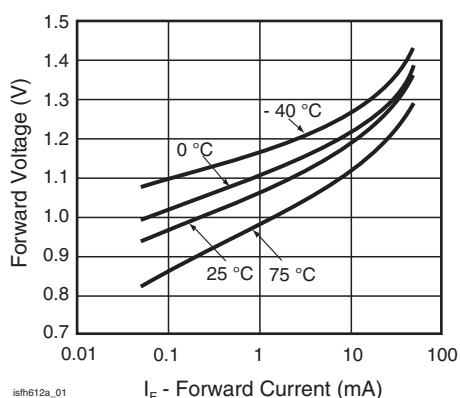


Fig. 4 - Forward Voltage vs. Forward Current

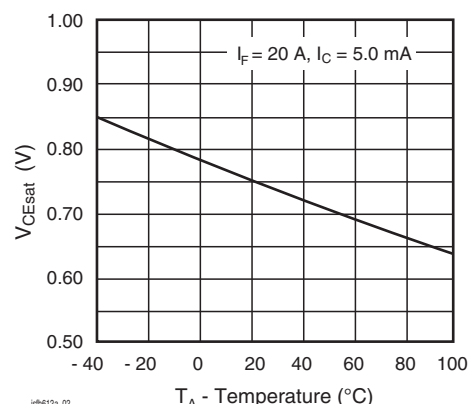


Fig. 5 - Collector Emitter Saturation Voltage vs. Temperature

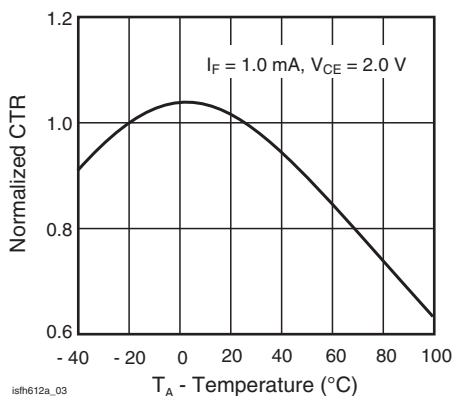


Fig. 6 - Normalized CTR vs. Temperature

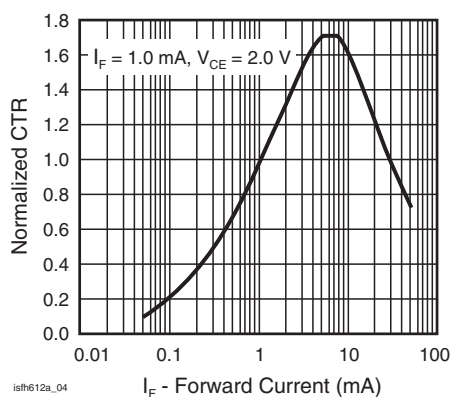


Fig. 7 - Normalized CTR vs. Forward Current

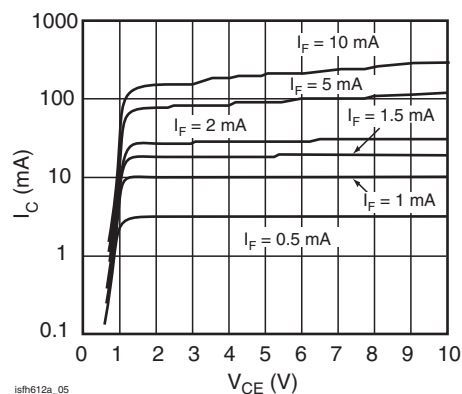


Fig. 8 - Collector Current vs. Collector Emitter Voltage

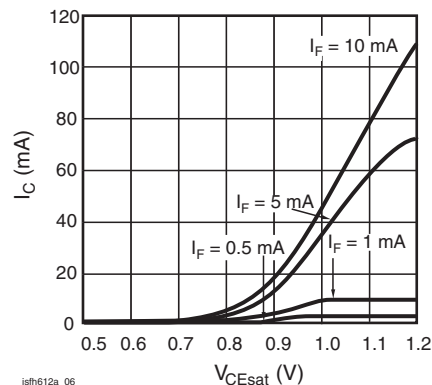


Fig. 9 - Collector Current vs. Collector Emitter Saturation Voltage

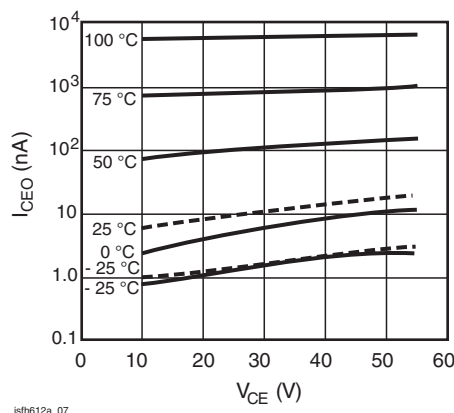


Fig. 10 - Collector Emitter Dark Current vs. Collector Emitter Voltage over Temperature

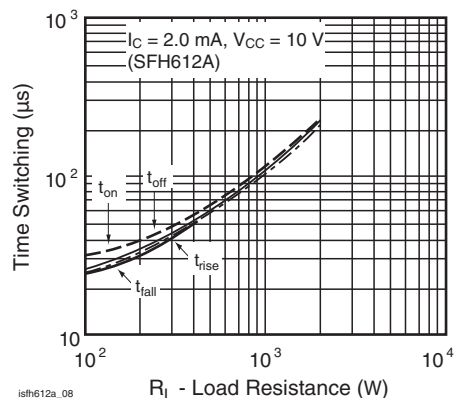


Fig. 11 - Switching Time vs. Load Resistor

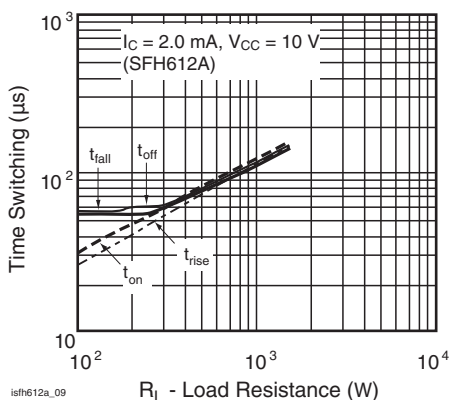


Fig. 12 - Switching Time vs. Load Resistor

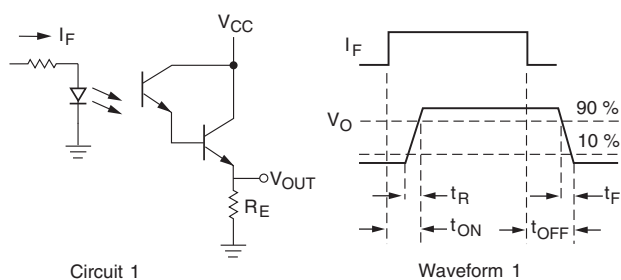


Fig. 13 - Switching Time Test Circuit and Waveforms

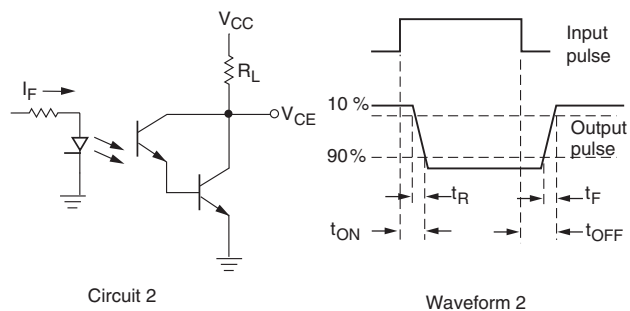
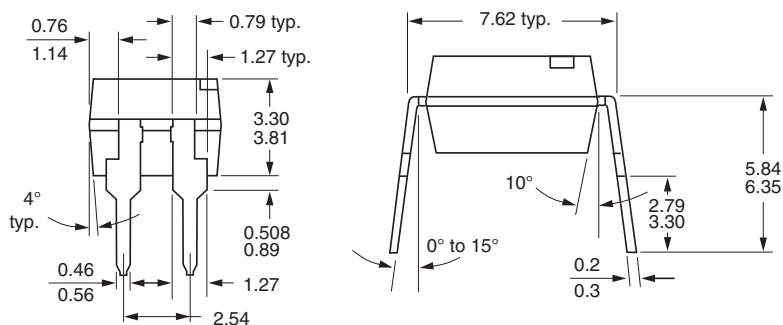
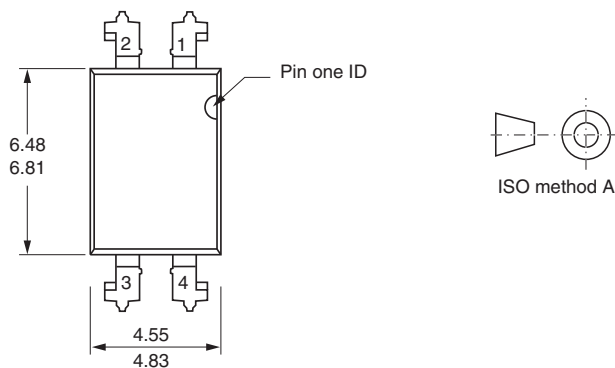


Fig. 14 - Switching Time Test Circuit and Waveforms

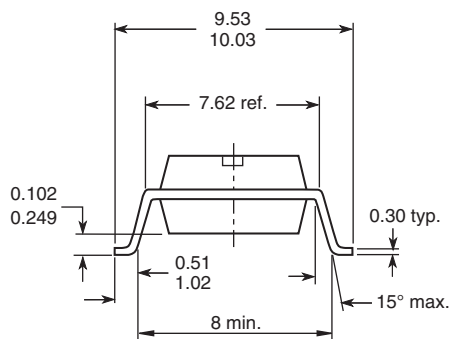


PACKAGE DIMENSIONS in millimeters



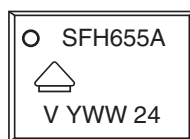
i178027

Option 9



18449

PACKAGE MARKING



Note

- VDE logo is only printed on option 1 parts. Option information is not marked on the part.



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